NSN 5962-01-221-8005

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View Online at https://aerobasegroup.com/nsn/5962-01-221-8005

0.840 inches	
Body Width:	
Between 0.220 inches and 0	.310 inches
Body Height:	
0.140 inches	
Maximum Power Dissipation	on Rating:
739.0 milliwatts	
Operating Tempurature Ra	nge:
-55.0 to 125.0 degrees celsion	JS
Storage Tempurature Rang	je:
-65.0 to 150.0 degrees celsion	JS
Features Provided:	
Schottky and bipolar and mo	nolithic and 3-state output and programmable
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Case Outline Source And I	Designator:
D-2 mil-m-38510	
Terminal Surface Treatmer	it:
Solder	
Voltage Rating And Type F	er Characteristic:
7.0 volts power source	
Time Rating Per Chacteris	tic:
80.00 nanoseconds propaga	ation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Test Data Document:	
96906-mil-std-883 standard	(includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quanti	ty:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

Yes - demil/mli

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